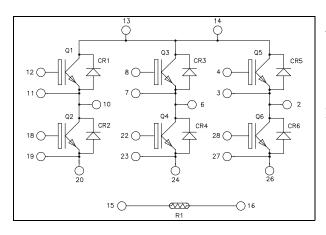
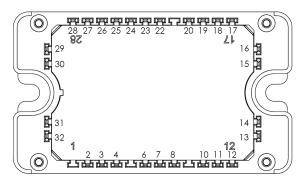


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Triple phase leg High speed Trenchstop 5 IGBT Power Module





Pins 20, 24 & 26 must be shorted together to perform a 3 phase bridge.

$V_{CES} = 650V$; $I_C = 50A$ @ $Tc = 25^{\circ}C$

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT5 technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Low leakage current
- Very low stray inductance
- Kelvin source for easy drive
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (Per IGBT)

Symbol	Parameter		Max ratings	Unit
V _{CES}	Collector - Emitter Voltage		650	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	50	
I _C		$T_C = 80^{\circ}C$	30	Α
I _{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	100	
V _{GE}	Gate – Emitter Voltage		± 20	V
P _D	Power Dissipation		125	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed.

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Electrical Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 650V$				50	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.65	2.2	V
V _{CE(sat)}		$I_C = 50A$	$T_{j} = 150^{\circ}C$		1.9		v
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 0.5 \text{mA}$		3.3	4.0	4.7	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				120	nA

Dynamic Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			3000		
Coes	Output Capacitance				50		pF
Cres	Reverse Transfer Capacitance	f = 1 MHz		11			
Q _G	Gate charge	$V_{GE} = 15V, I_C = V_{CE} = 520V$	= 50A		120		nC
T _{d(on)}	Turn-on Delay Time	Inductive Switching (25°C)			21		
Tr	Rise Time	$V_{GE} = 15V$			15		
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 400V$ $I_C = 25A$			180		ns
$T_{\rm f}$	Fall Time	$R_G = 12\Omega$		18			
T _{d(on)}	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 25A$ $R_G = 12\Omega$			20		
Tr	Rise Time				15		
T _{d(off)}	Turn-off Delay Time				205		ns
$T_{\rm f}$	Fall Time				26		
Eon	Turn on Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 25A$ $R_G = 12\Omega$	$T_j = 150^{\circ}C$		0.75		mJ
E _{off}	Turn off Energy		$T_j = 150^{\circ}C$		0.3		1115
R _{thJC}	Junction to Case Thermal Resistance					1.2	°C/W

Diode ratings and characteristics (per diode)

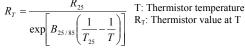
Symbol	Characteristic	Test Conditions			Тур	Max	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage					650	V	
I _{RM}	Reverse Leakage Current	V _R =650V				50	μA	
I _F	DC Forward Current		$Tc = 25^{\circ}C$		50		Α	
V	Diode Forward Voltage	$I_{\rm F} = 50 A$ $V_{\rm GE} = 0 V$	$T_i = 25^{\circ}C$		1.6	2.2	v	
$V_{\rm F}$		$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.65		v	
t _{rr}	Reverse Recovery Time	me $I_F = 25A$ $V_R = 400V$		$T_j = 25^{\circ}C$		46		ns
۰rr	Reverse Recovery Time		$T_{j} = 150^{\circ}C$		62		115	
0	O_{-} Reverse Recovery Charge $di/dt = 1500 A/\mu s$	$di/dt = 1500 A/\mu s$ $T_j = 25^{\circ} G$	$T_j = 25^{\circ}C$		0.5			
Qπ			$T_{j} = 150^{\circ}C$		1		μC	
R _{thJC}	Junction to Case Thermal Resistance					1.4	°C/W	



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Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

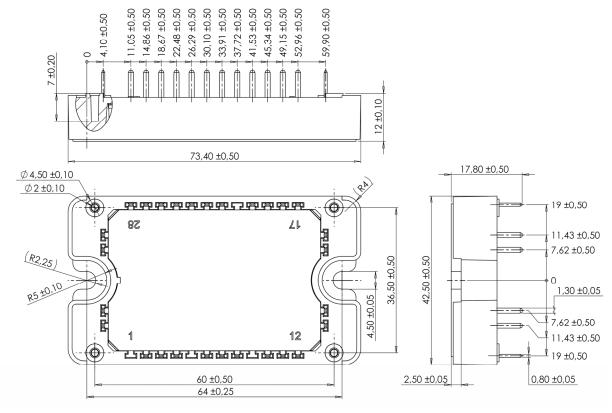
Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
$\Delta R_{25}/R_{25}$			5		%
B _{25/85}	$T_{25} = 298.15 \text{ K}$		3952		K
$\Delta B/B$	T _C =100°C		4		%
	R _a T. The second state to second second				



Package characteristics

Symbol	Characteristic			Min	Max	Unit
VISOL	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
T _J	Operating junction temperature range			-40	175	
T _{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C
T _{STG}	Storage Temperature Range			-40	125	C
T _C	Operating Case Temperature				125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

Package outline (dimensions in mm)



See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

www.microsemi.com

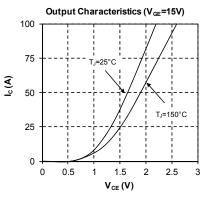
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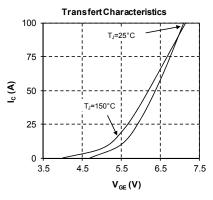
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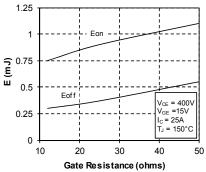
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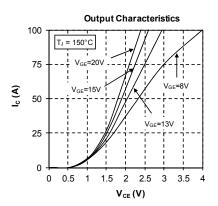
Typical Performance Curve





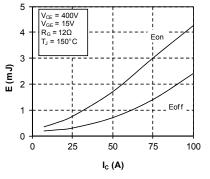
Switching EnergyLosses vs Gate Resistance



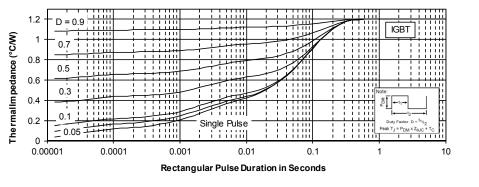


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Maxim um Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration

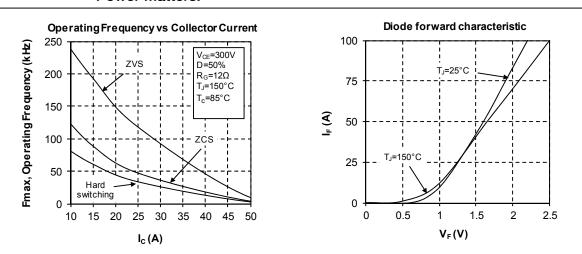


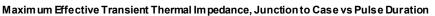
www.microsemi.com

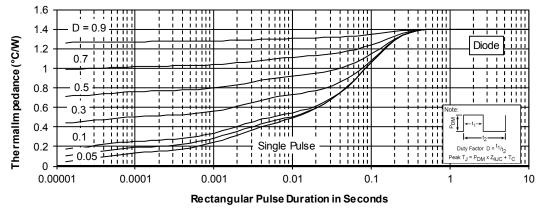
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